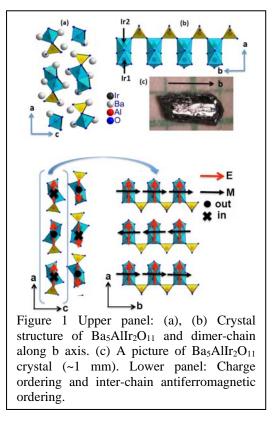
ESRF	Experiment title: Elementary excitations in the quasi-1D dimer-chain iridate Ba ₅ AlIr ₂ O ₁₁	Experiment number: HC-2566
Beamline:	Date of experiment:	Date of report:
	from: 13.04.2016 to: 19.04.2016	05.09.2016
Shifts:	Local contact(s):	Received at ESRF:
	Marco Moretti Sala	
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Report:

We have carried out resonant inelastic X-ray scattering (RIXS) experiment 'Elementary excitations in the quasi-1D dimer-chain iridate Ba₅AlIr₂O₁₁' (proposal HC-2566) on ID20 of ESRF. We find that the quasi-1D dimer chain Ba₅AlIr₂O₁₁ bearing mixing valence states (Ir⁴⁺ and Ir⁵⁺) [1] shows much more complicated crystal field excitations than typical Ir⁴⁺ systems, which is caused by electronic transitions between the electronic levels within t_{2g} orbitals of the molecular clusters.

Ba₅AlIr₂O₁₁ consists of dimer-chains lying along the *b* axis, with the dimers containing two face-sharing IrO₆ octahedra, which are weakly connected by AlO₄ tetrahedra, while the dimer-chains are well separated. This structure characteristically generates weak intra-chain interactions between dimers and even weaker interchain couplings. The system shows different local distortions for Ir1-O and Ir2-O octahedra, with slight differences in the Ir-O bond length, indicating a more complicated non-cubic crystal electric field within the isolated dimer [1].

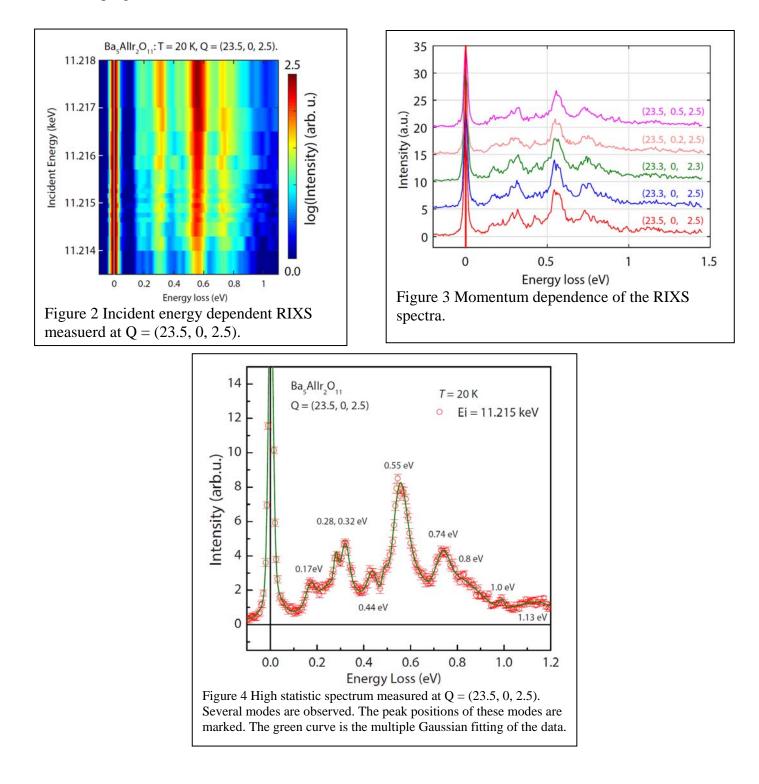
The incident energy dependent RIXS spectra shown in Fig. 2 reveals various Raman modes corresponding to low energy crystal field excitations within t_{2g} orbitals, ranging from ~0.2eV to ~1.3eV. We have also observed $t_{2g}-e_g$ transitions at ~3eV (not



shown here). These Raman modes within t_{2g} orbitals are quite narrow in energy and not followed by any fluorescence. Moreover, Ba₅AlIr₂O₁₁ is a strong Mott insulator, indicative of a large insulating gap. Therefore, we attribute these Raman modes to the local modes arising from the transitions between the electronic levels within t_{2g} orbitals of the dimer molecular clusters.

As a result of the difference in local distortion and underlying electronic interactions, the system shows partial charge disproportion (Ir1 is closer to Ir^{5+} and Ir2 to Ir^{4+}), indicative of a charge order (below 210 K). However, our momentum dependent RIXS measurements shown in Fig. 2 do not show any collective excitations. All the Raman modes we observed are dispersiveless (local modes). This could be ascribed to the weak electronic interactions between the dimers.

To quantitatively determine the crystal field excitations shown in Fig. 2 and 3, we have performed high statistic RIXS measurements at Q = (23.5, 0, 2.5). The spectrum and its fitting by multi-gaussians are shown in Fig. 4. About 10 Raman modes have been identified between 0.1eV and 1.2eV, indicating that rich electronic levels are formed in the t_{2g} orbitals of this system. No modes were observed between 1.2eV and $t_{2g}-e_g$ transitions. Quantitative analysis of the microscopic origin of these low energy crystal field excitations are still in progress.



Reference:

^[1] J. Terzic et al., Phys. Rev. B 91, 235147 (2015).